

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (U-MOSIV)

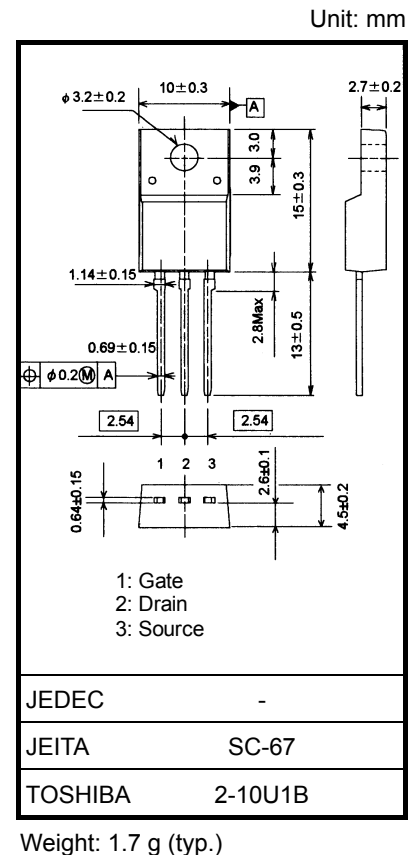
TK80A08K3

Switching Regulator Applications

- Low drain-source ON-resistance: $R_{DS(ON)} = 3.6 \text{ m}\Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 200 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \text{ }\mu\text{A}$ (max) ($V_{DS} = 75 \text{ V}$)
- Enhancement mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Characteristics | | Symbol | Rating | Unit |
|--|----------------|-----------|------------|------------------|
| Drain-source voltage | | V_{DSS} | 75 | V |
| Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$) | | V_{DGR} | 75 | V |
| Gate-source voltage | | V_{GSS} | ± 20 | V |
| Drain current | DC (Note 1) | I_D | 80 | A |
| | Pulse (Note 1) | I_{DP} | 320 | |
| Drain power dissipation ($T_c = 25^\circ\text{C}$) | | P_D | 40 | W |
| Single pulse avalanche energy (Note 2) | | E_{AS} | 443 | mJ |
| Avalanche current | | I_{AR} | 80 | A |
| Repetitive avalanche energy (Note 3) | | E_{AR} | 4 | mJ |
| Channel temperature | | T_{ch} | 150 | $^\circ\text{C}$ |
| Storage temperature range | | T_{stg} | -55 to 150 | $^\circ\text{C}$ |



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|--|----------------|-------|--------------------|
| Thermal resistance, channel to case | $R_{th(ch-c)}$ | 3.125 | $^\circ\text{C/W}$ |
| Thermal resistance, channel to ambient | $R_{th(ch-a)}$ | 62.5 | $^\circ\text{C/W}$ |

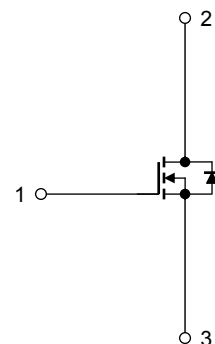
Note 1: Ensure that the channel and lead temperatures do not exceed 150°C .

Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^\circ\text{C}$, $L = 100 \text{ }\mu\text{H}$, $I_{AR} = 80 \text{ A}$, $R_G = 1 \text{ }\Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.

Internal Connection



Electrical Characteristics (Ta = 25°C)

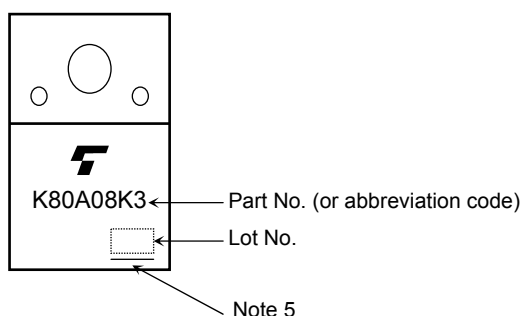
| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---------------|---------------|---|-----|------|---------|------------------|
| Gate leakage current | | I_{GSS} | $V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$ | — | — | ± 1 | μA |
| Drain cut-off current | | I_{DSS} | $V_{DS} = 75\text{ V}, V_{GS} = 0\text{ V}$ | — | — | 10 | μA |
| Drain-source breakdown voltage | | $V_{(BR)DSS}$ | $I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$ | 75 | — | — | V |
| | | $V_{(BR)DSX}$ | $I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$ | 50 | — | — | |
| Gate threshold voltage | | V_{th} | $V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$ | 2.0 | — | 4.0 | V |
| Drain-source ON-resistance (Note 4) | | $R_{DS(ON)}$ | $V_{GS} = 10\text{ V}, I_D = 40\text{ A}$ | — | 3.6 | 4.5 | $\text{m}\Omega$ |
| Forward transfer admittance | | $ Y_{fs} $ | $V_{DS} = 10\text{ V}, I_D = 40\text{ A}$ | 100 | 200 | — | S |
| Input capacitance | | C_{iss} | $V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$ | — | 8200 | — | pF |
| Reverse transfer capacitance | | C_{rss} | | — | 770 | — | |
| Output capacitance | | C_{oss} | | — | 1140 | — | |
| Switching time | Rise time | t_r | | — | 30 | — | ns |
| | Turn-ON time | t_{on} | | — | 55 | — | |
| | Fall time | t_f | | — | 33 | — | |
| | Turn-OFF time | t_{off} | | — | 150 | — | |
| Total gate charge (gate-source plus gate-drain) | | Q_g | $V_{DD} \approx 60\text{ V}, V_{GS} = 10\text{ V}, I_D = 80\text{ A}$ | — | 175 | — | nC |
| Gate-source charge 1 | | Q_{gs1} | | — | 40 | — | |
| Gate-drain ("miller") charge | | Q_{gd} | | — | 65 | — | |
| Gate switch charge | | Q_{sw} | | — | 80 | — | |

Note 4: Measured at lead standoff.

Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|------|------|
| Continuous drain reverse current (Note 1) | I_{DR} | — | — | — | 80 | A |
| Pulse drain reverse current (Note 1) | I_{DRP} | — | — | — | 320 | A |
| Forward voltage (diode) | V_{DSF} | $I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V}$ | — | -0.9 | -1.2 | V |
| Reverse recovery time | t_{rr} | $I_{DR} = 80\text{ A}, V_{GS} = 0\text{ V},$ | — | 60 | — | ns |
| Reverse recovery charge | Q_{rr} | $dI_{DR}/dt = 50\text{ A}/\mu\text{s}$ | — | 60 | — | nC |

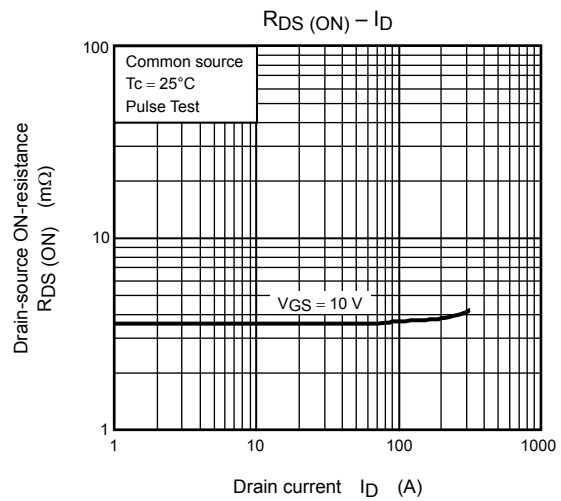
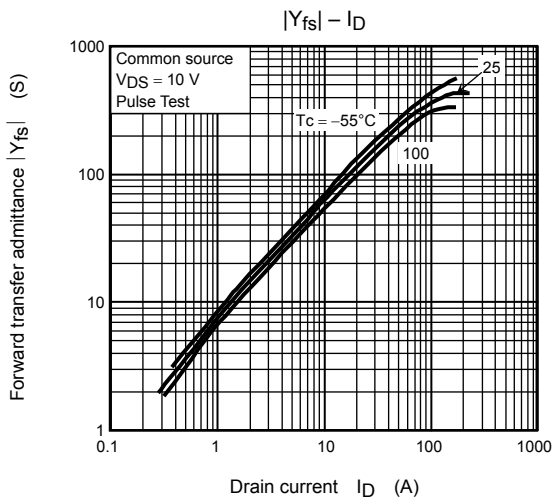
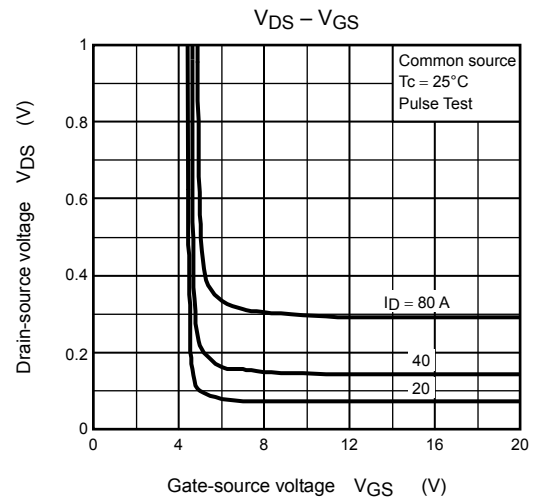
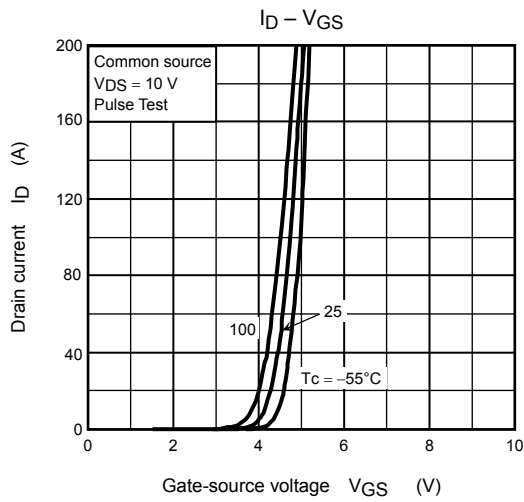
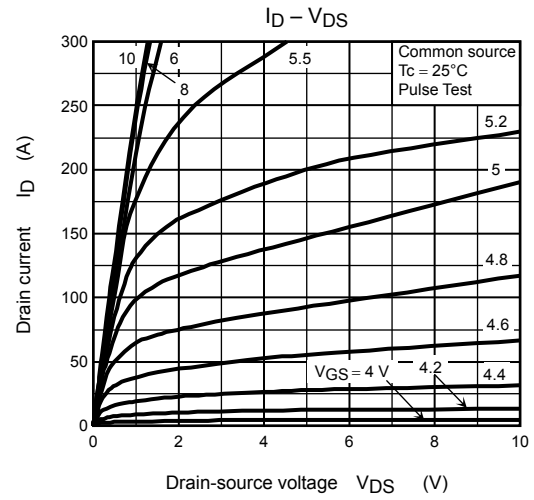
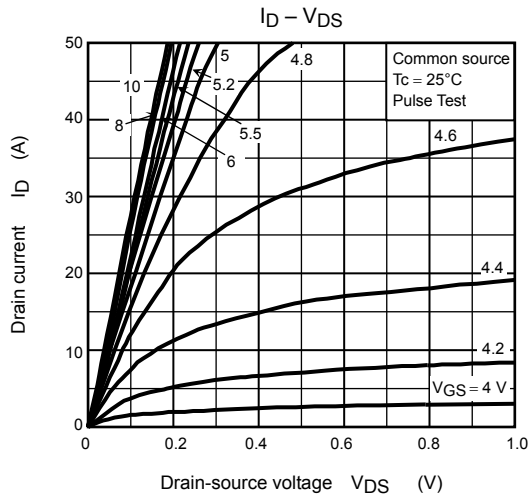
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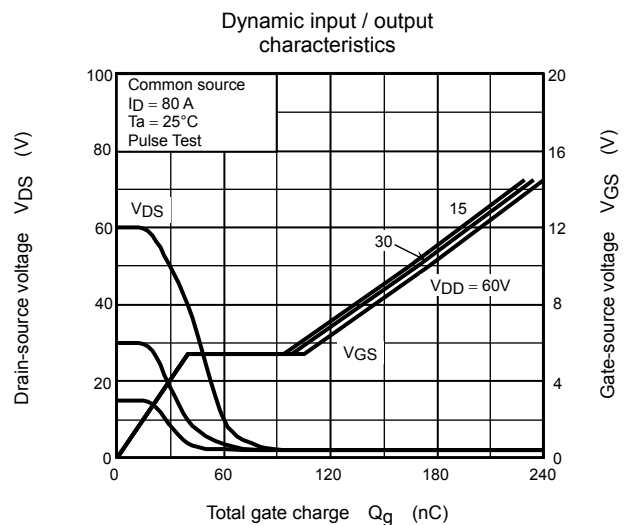
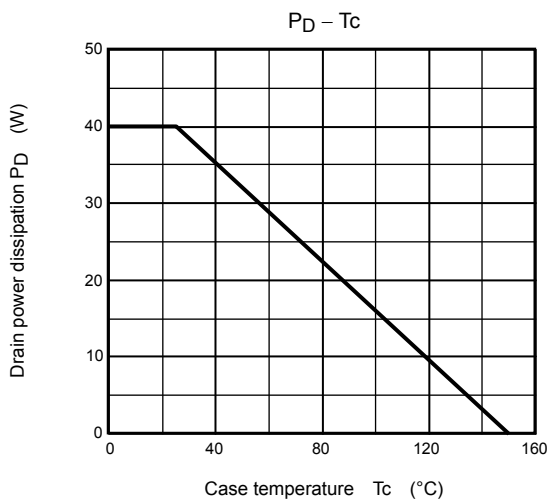
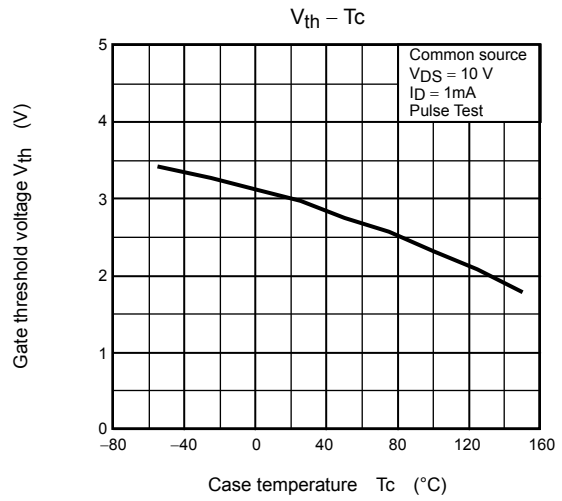
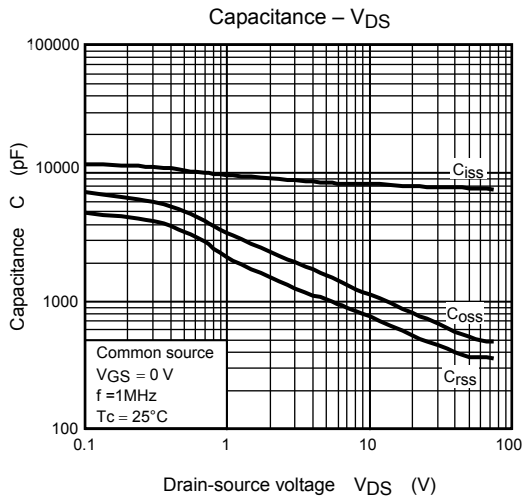
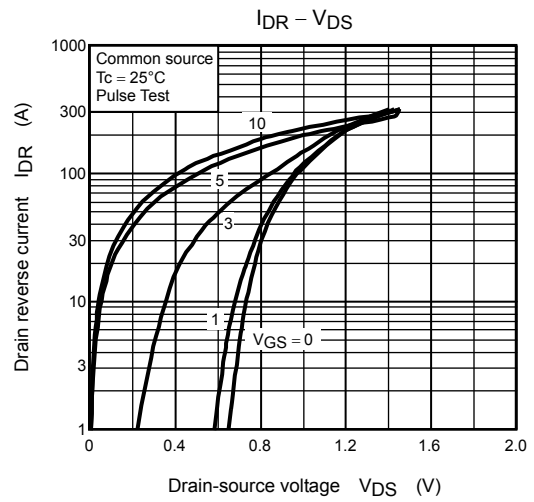
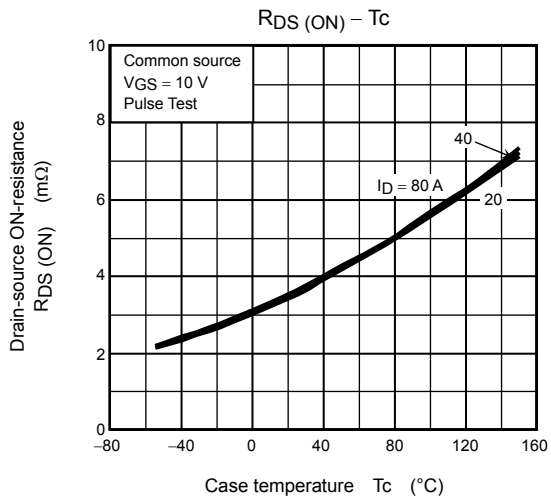


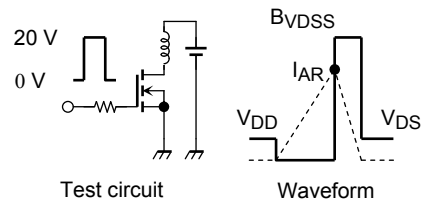
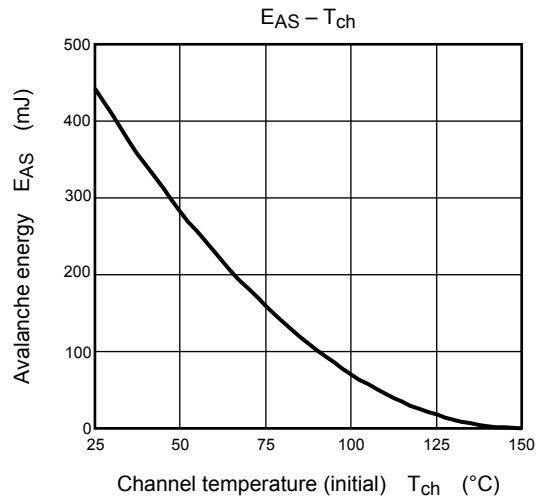
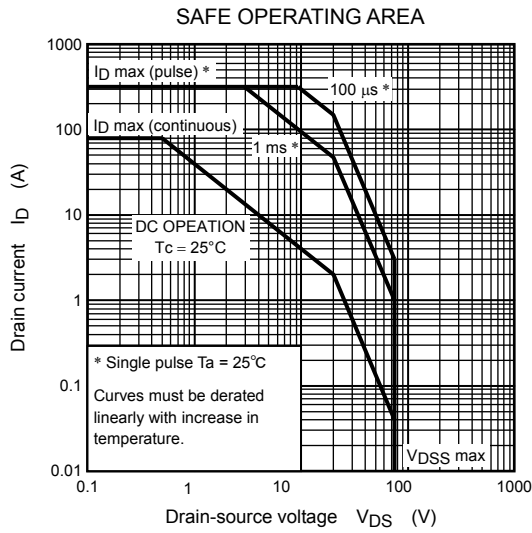
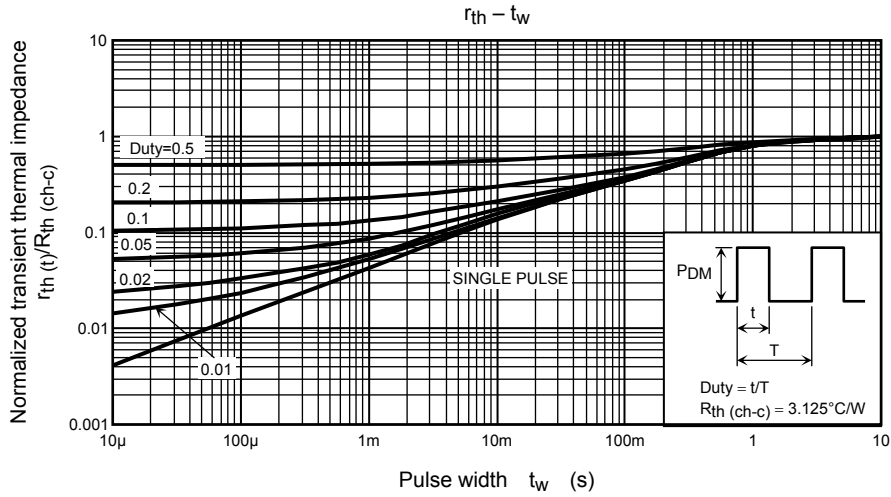
Note 5: A line under a Lot No. identifies the indication of product Labels.

[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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$R_G = 1 \Omega$
 $V_{DD} = 25 \text{ V}, L = 100 \mu\text{H}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{BVDSS}{BVDSS - V_{DD}} \right)$$

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